

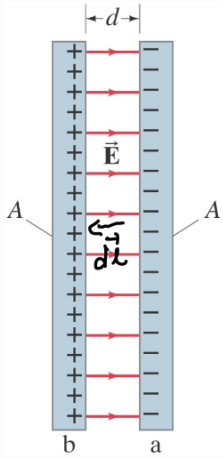
Chapter 24: Capacitance and Energy Storage

Capacitance:

$$Q = CV$$

$\hookrightarrow$ capacitance

$$C = \frac{Q}{V}, \text{ measured in SI in } C/V (\text{farad}).$$



* A single plate has $E = \frac{\sigma}{2\epsilon_0} = \frac{Q}{2A\epsilon_0}$.

* A parallel plate capacitor has $E = Q/A\epsilon_0$.

$$V = - \int_b^a \vec{E} \cdot d\vec{\ell} = V_b - V_a = \int_b^a E d\ell = E \int_b^a d\ell = Ed = \frac{Qd}{A\epsilon_0}$$

$$C = Q/V = A\epsilon_0/d$$

Example 24.1

$$A = (20 \times 10^{-2} \text{ m})(3 \times 10^{-2} \text{ m})$$

$$d = 10^{-3} \text{ m}$$

$$V = 12 \text{ V}$$

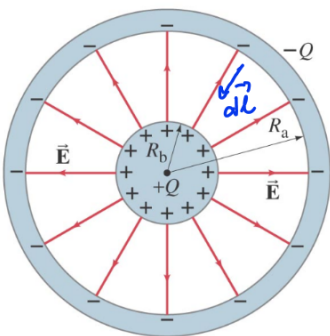
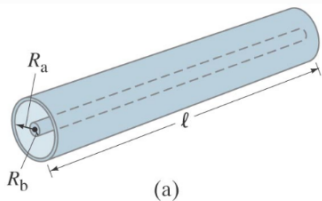
$$\epsilon_0 = 8.85 \times 10^{-12} \text{ C}^2/\text{Nm}^2$$

a) $C = A\epsilon_0/d = 53 \times 10^{-12} \text{ F}$

b) $Q = CV = 6.4 \times 10^{-10} \text{ C}$

c) $E = V/d = 1.2 \times 10^4 \text{ V/m}$

Example 24.2



$\vec{E}$ -field in the region $R_b < r < R_a$: use Gauss's law.

$$\oint \vec{E} \cdot d\vec{A} = Q_{enc}/\epsilon_0 \Rightarrow E 2\pi R l = \lambda l / \epsilon_0 \Rightarrow E = \frac{\lambda}{2\pi\epsilon_0} \frac{1}{R}$$

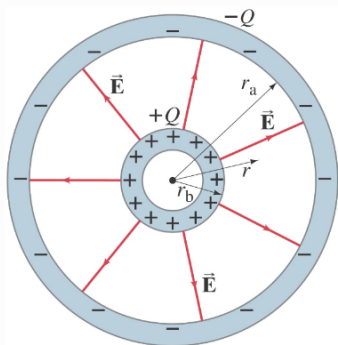
$$E = \frac{1}{2\pi\epsilon_0} \frac{Q}{lR}$$

$$V_b - V_a = - \int_a^b \vec{E} \cdot d\vec{\ell} = - \frac{Q}{2\pi\epsilon_0 l} \int_{R_a}^{R_b} \frac{dR}{R} = - \frac{Q}{2\pi\epsilon_0 l} \ln \frac{R_b}{R_a}$$

$$V = \frac{Q}{2\pi\epsilon_0 l} \ln \frac{R_a}{R_b}, \quad C = Q/V$$

$$C = \frac{2\pi\epsilon_0 l}{\ln(R_a/R_b)}$$

Example 24.3

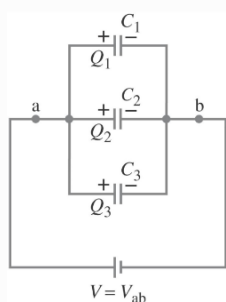


$\vec{E}$ -field in $r_b < r < r_a$: $E(r) = \frac{Q}{4\pi\epsilon_0} \frac{1}{r^2}$

$$V_b - V_a = - \int_a^b \vec{E} \cdot d\vec{l} = - \frac{Q}{4\pi\epsilon_0} \int_{r_a}^{r_b} \frac{dr}{r^2} = \frac{Q}{4\pi\epsilon_0} \left(\frac{1}{r_b} - \frac{1}{r_a} \right)$$

$$V = \frac{Q}{4\pi\epsilon_0} \left(\frac{r_a - r_b}{r_a r_b} \right), \quad C = \frac{Q}{V} = 4\pi\epsilon_0 \left(\frac{r_a r_b}{r_a - r_b} \right)$$

Capacitors in Series and Parallel:

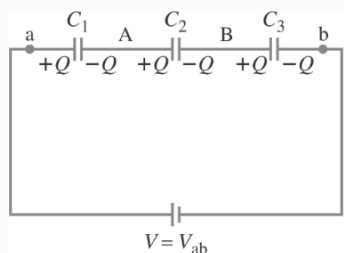


Parallel Configuration

$$Q = Q_1 + Q_2 + Q_3 = C_1 V + C_2 V + C_3 V = (C_1 + C_2 + C_3) V$$

$$Q = C_{eq} V = (C_1 + C_2 + C_3) V \Rightarrow C_{eq} = C_1 + C_2 + C_3$$

Series Configuration



$$V = V_1 + V_2 + V_3, \quad Q = C_1 V_1 = C_2 V_2 = C_3 V_3$$

$$Q = C_{eq} V \Rightarrow V = Q / C_{eq} = Q / C_1 + Q / C_2 + Q / C_3$$

$$1 / C_{eq} = 1 / C_1 + 1 / C_2 + 1 / C_3$$

Electric Energy Storage:

$$\int dW = \int_0^Q V dq \Rightarrow W = U = \frac{1}{C} \int_0^Q q dq \Rightarrow U = \frac{1}{2} \frac{Q^2}{C}$$

$$V = q / C \Rightarrow U = \frac{1}{2} C V^2 = \frac{1}{2} Q V$$

Example 24.8

a) $U = \frac{1}{2} C V^2 \Rightarrow U = \frac{1}{2} (157 \times 10^{-6} \text{ F}) (200 \text{ V})^2 = 3.0 \text{ J}$

b) $P = U / \Delta t \Rightarrow P = 3.0 \text{ J} / 10^{-3} \text{ s} = 3000 \text{ W}$

Example 24.9

$$\left. \begin{array}{l} Q \rightarrow \text{constant} \\ C = \frac{A\epsilon_0}{d} \end{array} \right\}$$

2↓ d ↑2

Increases by a factor of 2 $U = \frac{1}{2} \frac{Q^2}{C}$ $\xrightarrow{\text{constant}}$ drops by a factor of 2

Energy Density:

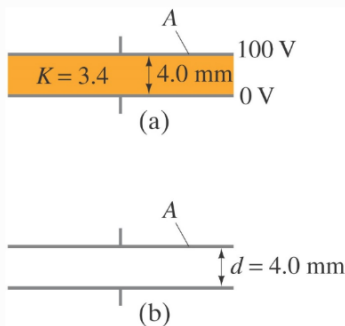
* consider the parallel plate capacitor. $C = A\epsilon_0/d$ and $V = Ed$

$$U = \frac{1}{2} CV^2 = \frac{1}{2} \left(\frac{A\epsilon_0}{d} \right) (Ed)^2 = \frac{1}{2} \epsilon_0 E^2 \underbrace{Ad}_{\text{Volume}} \Rightarrow U = \frac{\text{energy}}{\text{Volume}} = \frac{1}{2} \epsilon_0 E^2$$

Dielectrics:

* In a parallel plate capacitor, $C = \underbrace{K}_{\text{permittivity}} \epsilon_0 \frac{A}{d}$

Example 24.11



$$a) \quad C = K\epsilon_0 \frac{A}{d} = 3.0 \times 10^{-8} \text{ F} \quad Q = CV = 3.0 \times 10^{-6} \text{ C}$$

$$E = V/d = 25 \times 10^3 \text{ V/m} \quad U = \frac{1}{2} CV^2 = 1.5 \times 10^{-4} \text{ J}$$

$$b) \quad C_0 = C/K \quad \text{-----}$$